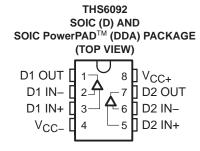
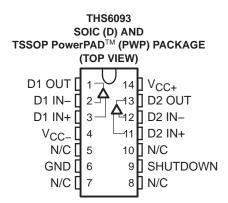
- Remote Terminal ADSL Line Driver
 - Ideal for Both Full Rate ADSL and G.Lite
 - Compatible With 1:2 Transformer Ratio
- Wide Supply Voltage Range +5 V to +14 V
 - Ideal for Single Supply +12-V Operation
 - Low 2.1 pA/√Hz Noninverting Current Noise

 Reduces Noise Feedback Through
 Hybrid Into Downstream Channel
- Wide Output Swing
 - 18.4 Vpp Differential Output Voltage, R_I = 50 Ω , 12-V Single Supply
- High Output Current
 - 275 mA (typ)



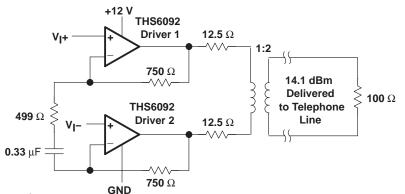
High Speed

- 100 MHz (-3 dB, G=1, 12-V Single Supply)
- 600 V/μs Slew Rate (G = 4, 12-V Single Supply)
- Low Distortion, Single-Ended, G = 4
 - 72 dBc (250 kHz, 2 Vpp, 25 Ω load)
 - 78 dBc (250 kHz, 2 Vpp, 100 Ω load)
- Low Power Shutdown (THS6093)
 - 300 μA Total Standby Current
- Thermal Shutdown and Short Circuit Protection
- Standard SOIC, SOIC PowerPAD™, and TSSOP PowerPAD™ Package
- Evaluation Module Available



description

The THS6092/3 is a high-speed line driver ideal for driving signals from the remote terminal to the central office in asymmetrical digital subscriber line (ADSL) applications. It can operate from a single +12-V supply voltage while drawing only 7.3 mA of supply current per channel. It offers low –72 dBc total harmonic distortion driving a 25- Ω load (2 Vpp). The THS6092/3 offers a high 18.4-Vpp differential output swing across a 50- Ω load from a single +12-V supply. The THS6093 features a low-power shutdown mode, consuming only 300 μ A quiescent current per channel. The THS6092/3 is packaged in a standard SOIC, SOIC PowerPADTM, and TSSOP PowerPADTM package.



RELATED PRODUCTS

DEVICE	DESCRIPTION
THS6042/3	350-mA, ±12 ADSL CPE line driver
THS6052/3	175-mA, ±12 V ADSL CPE line driver
OPA2677	380-mA, +12 V ADSL CPE line driver
THS6062	Low noise ADSL receiver



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PowerPAD is a trademark of Texas Instruments.

TEXAS INSTRUMENTS

SLOS345C - JANUARY 2001 - REVISED OCTOBER 2002

AVAILABLE OPTIONS

	PACKAGED DEVICE						
TA	SOIC-8† (D)	SOIC-8† PowerPAD (DDA)	SOIC-14 [†] (D)	TSSOP-14 [†] PowerPAD (PWP)	EVALUATION MODULES		
0°C to 70°C	THS6092CD	THS6092CDDA	THS6093CD	THS6093CPWP	THS6092EVM THS6093EVM		
-40°C to 85°C	THS6092ID	THS6092IDDA	THS6093ID	THS6093IPWP	_		

[†] All packages are available taped and reeled. Add an R-suffix to the device type (i.e., THS6092IDR).

absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Supply voltage, V _{CC+} to V _{CC-}	14.7 V
Input voltage	
Output current (see Note 1)	350 mA
Differential input voltage	± 3 V
Maximum junction temperature	150°C
Total power dissipation at (or below) 25°C free-air temperature	See Dissipation Ratings Table
Operating free-air temperature, T _A : Commercial	
Industrial	–40°C to 85°C
Storage temperature, T _{stq} : Commercial	–65°C to 125°C
Industrial	
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	300°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The THS6092 and THS6093 may incorporate a PowerPAD™ on the underside of the chip. This acts as a heatsink and must be connected to a thermally dissipating plane for proper power dissipation. Failure to do so may result in exceeding the maximum junction temperature which could permanently damage the device. See TI Technical Brief SLMA002 for more information about utilizing the PowerPAD™ thermally enhanced package.

DISSIPATION RATING TABLE

PACKAGE	θЈА	θЈС	T _A = 25°C§ POWER RATING	T _A = 70°C§ POWER RATING	T _A = 85°C§ POWER RATING
D-8	95°C/W [‡]	38.3°C/W [‡]	1.1 W	0.63 W	0.47 W
DDA	45.8°C/W	9.2°C/W	2.3 W	1.31 W	0.98 W
D-14	66.6°C/W‡	26.9°C/W‡	1.6 W	0.90 W	0.68 W
PWP	37.5°C/W	1.4°C/W	2.8 W	1.60 W	1.20 W

[‡] This data was taken using the JEDEC proposed high-K test PCB. For the JEDEC low-K test PCB, the Θ_{JA} is168°C/W for the D–8 package and 122.3°C/W for the D–14 package.

recommended operating conditions

		MIN	NOM MAX	UNIT
Supply voltage, V _{CC+} to V _{CC-}	Dual supply	±2.5	±7	.,
	Single supply	+5	+14	V
On and the office of the control of T	C-suffix	0	70	
Operating free-air temperature, T _A	I-suffix	-40	85	°C



[§] Power rating is determined with a junction temperature of 130°C. This is the point where distortion starts to substantially increase. Thermal management of the final PCB should strive to keep the junction temperature at or below 125°C for best performance.

electrical characteristics over recommended operating free-air temperature range, T_A = 25°C, V_{CC+} = 12 V, V_{CC-} = GND, R_{FEEDBACK} = 750 Ω , R_L = 25 Ω (unless otherwise noted)

dynamic performance

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
BW Small-signal bandwidth (-3 dB) G=1	V _{CC} = 12 V		100		NAL I-	
	Small-signal bandwidth (-3 dB) G=1	V _{CC} = 5 V		90		MHz
CD	Claurate (see Note 2)	V _{CC} = 12 V		600		1//
SR	Slew rate (see Note 2)	V _{CC} = 5 V		400		V/μs

NOTE 2: Slew rate is defined from the 25% to the 75% output levels.

noise/distortion performance

	PARAMETER			TEST CONDITIONS			TYP	MAX	UNIT	
	Total harmonic disto	Total harmonic distortion		$R_L = 25 \Omega$, f = 250 kHz	V _{O(pp)} = 2 V		-70			
THD	(single-ended configurat	guration)	Gain = 4,	R _L = 25 Ω,	V _{O(pp)} = 2 V		-72		dBc	
			$V_{CC} = 12 \text{ V}, f = 250 \text{ kHz}$		V _{O(pp)=7} V		-68			
Vn	Input voltage noise		V _{CC} = 12 V,	V _{CC} = 12 V, 5 V, f = 10 kHz			2.1		nV/√Hz	
	Input ourrent noise	+Input	V00 - 12 V	/ _{CC} = 12 V, 5 V, f = 10 kHz			2.1		pA/√Hz	
^I n	Input current noise	-Input	$ACC = 15 A^{\circ}$	5 V, I = 10 KHZ			10.9		pA/√HZ	
X _T	Crosstalk	0 4		$V_O = 2 \text{ Vpp}$ $R_L = 25 \Omega$	V _{CC} = 5 V		-65		dBc	
'					V _{CC} = 12 V		-63			

dc performance

	PARAMETER	TEST C	ONDITIONS	MIN	TYP	MAX	UNIT
	long to effect yeltogo		T _A = 25°C		6	16	
	Input offset voltage		T _A = full range			21	mV
Vos	Differential effect voltage	V _{CC} = 12 V, 5 V	T _A = 25°C		1	6	
	Differential offset voltage		T _A = full range			8	
	Offset drift		T _A = full range		20		μV/°C
	- Input bias current		T _A = 25°C		3	10	
			T _A = full range			12	
l.o.	I loout bigg gurrant	Voc - 12 V 5 V	T _A = 25°C		1	6	^
ΙΒ	+ Input bias current	V _{CC} = 12 V, 5 V	T _A = full range			7	μΑ
	Differential input bias current		T _A = 25°C		3	10	
	Differential input bias current		T _A = full range			12	
ZOL	Open loop transimpedance	$R_L = 1 k\Omega$	V _{CC} = 12 V, 5 V		0.9		$M\Omega$

SLOS345C - JANUARY 2001 - REVISED OCTOBER 2002

electrical characteristics over recommended operating free-air temperature range, T_A = 25°C, V_{CC+} = 12 V, V_{CC-} = GND, R_{FEEDBACK} = 750 Ω , R_L = 25 Ω (unless otherwise noted) (continued)

input characteristics

	PARAMETER	TEST COND	TEST CONDITIONS		TYP	MAX	UNIT
		Vaa EV	T _A = 25°C	1.5 to 3.5	1.1 to 3.9		
\/	lanut common mode voltege renge	V _{CC} = 5 V	T _A = full range	1.6 to 3.4			V
VICR	Input common-mode voltage range	Va = 42 V	T _A = 25°C	2.3 to 9.7	1.8 to 10.2		V
		V _{CC} = 12 V	T _A = full range	2.4 to 9.6			
		V _{CC} = 5 V	T _A = 25°C	56	63		
CMRR	Occurred to the section of the section		T _A = full range	54			dB
CIVIKK	Common-mode rejection ratio	10.1/	T _A = 25°C	50	56		uБ
		V _{CC} = 12 V	T _A = full range	48			
р.	Input registance	+ Input			1		MΩ
R _I	Input resistance	-Input	·		15		Ω
CI	Input capacitance				2		pF

output characteristics

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT	
			D 05.0	V _{CC} = 5 V	1.4 to 3.6	1.1 to 3.9		
.,	Vo. Output voltage swing	Single ended	$R_L = 25 \Omega$	V _{CC} = 12 V	1.9 to 10.1	1.4 to 10.6		.,
VO Output voltage swing	100 mV overdrive	D 400.0	V _{CC} = 5 V	1.3 to 3.7	1.05 to 3.95		·	
			$R_L = 100 \Omega$	V _{CC} = 12 V	1.5 to 10.5	1.1 to 10.9		
	Output summer!		$R_L = 3.6 \Omega$,	V _{CC} = 5 V		240		4
IO	Output current		$R_L = 10 \Omega$,	V _{CC} = 12 V	240	275		mA
Isc	Short-circuit current		$R_L = 0 \Omega$,	V _{CC} = 12 V		325		mA
	Output resistance		Open loop			15		Ω

power supply

	PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V	On a ratio a range	Dual supply					±7	
VCC	Operating range	Single supply			4.5		14	V
			V _{CC} = 5 V	T _A = 25°C		6.7	8.8	A
loo	Outlement ourment (analy driver)	Outros of comment (see the driver)		T _A = full range			10	mA
Icc	Quiescent current (each driver)		V 40 V	T _A = 25°C		7.3	9.5	
			V _{CC} = 12 V	T _A = full range			10.5	mA
				T _A = 25°C	-54	-58		
DODD	Barrara area la resta esta e resta		$V_{CC} = 5 V$	T _A = full range	-46	-		10
PSRR	Power supply rejection ratio		1011	T _A = 25°C	-58	-70		dB
			V _{CC} = 12 V	T _A = full range	-50			



SLOS345C - JANUARY 2001 - REVISED OCTOBER 2002

electrical characteristics over recommended operating free-air temperature range, T_A = 25°C, V_{CC+} = 12 V, V_{CC-} = GND, R_{FEEDBACK} = 750 Ω , R_L = 25 Ω (unless otherwise noted) (continued)

shutdown characteristics (THS6093 only)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
VIL(SHDN)	Shutdown pin voltage for power up	V _{CC} = 12 V, GND = 6 V (GND Pin as Reference)			0.8	٧
VIH(SHDN)	Shutdown pin voltage for power down	V _{CC} = 12 V, GND = 6 V (GND Pin as Reference)	2			٧
ICC(SHDN)	Total quiescent current when in shutdown state	V _{SHDN} = 8 V, V _{GND} = 6 V, V _{CC} = 12 V		0.3	0.7	mA
tDIS	Disable time (see Note 3)	V _{CC} = 12 V		0.2		μs
tEN	Enable time (see Note 3)	V _{CC} = 12 V		0.5		μs
I _{IL} (SHDN)	Shutdown pin input bias current for power up	V _{SHDN} = 6 V, V _{GND} = 6 V, V _{CC} = 12 V		40	100	μА
IH(SHDN)	Shutdown pin input bias current for power down	V _{SHDN} = 9.3 V, V _{GND} = 6 V, V _{CC} = 12 V		50	100	μΑ

NOTE 3: Disable/enable time is defined as the time from when the shutdown signal is applied to the SHDN pin to when the supply current has reached half of its final value.

APPLICATION INFORMATION

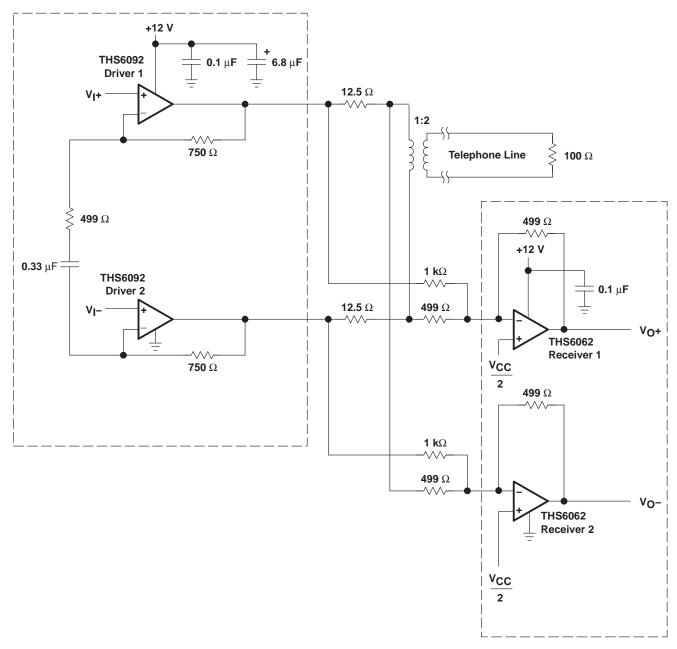


Figure 1. THS6092 ADSL Application With 1:2 Transformer Ratio

www.ti.com 23-May-2025

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
	(1)	(2)			(3)	(4)	(5)		(6)
THS6092ID	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	60921
THS6092ID.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	60921
THS6093CPWPR	Active	Production	HTSSOP (PWP) 14	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	0 to 70	HS6093C
THS6093CPWPR.A	Active	Production	HTSSOP (PWP) 14	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	HS6093C
THS6093IPWP	Active	Production	HTSSOP (PWP) 14	90 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	HS6093I
THS6093IPWP.A	Active	Production	HTSSOP (PWP) 14	90 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	HS6093I
THS6093IPWPR	Active	Production	HTSSOP (PWP) 14	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	HS6093I
THS6093IPWPR.A	Active	Production	HTSSOP (PWP) 14	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	HS6093I

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE OPTION ADDENDUM

www.ti.com 23-May-2025

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 23-May-2025

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
THS6093CPWPR	HTSSOP	PWP	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
THS6093IPWPR	HTSSOP	PWP	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

PACKAGE MATERIALS INFORMATION

www.ti.com 23-May-2025



*All dimensions are nominal

	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
	THS6093CPWPR	HTSSOP	PWP	14	2000	350.0	350.0	43.0	
ĺ	THS6093IPWPR	HTSSOP	PWP	14	2000	350.0	350.0	43.0	

PACKAGE MATERIALS INFORMATION

www.ti.com 23-May-2025

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
THS6092ID	D	SOIC	8	75	505.46	6.76	3810	4
THS6092ID.A	D	SOIC	8	75	505.46	6.76	3810	4
THS6093IPWP	PWP	HTSSOP	14	90	530	10.2	3600	3.5
THS6093IPWP.A	PWP	HTSSOP	14	90	530	10.2	3600	3.5

4.4 x 5.0, 0.65 mm pitch

PLASTIC SMALL OUTLINE

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



INSTRUMENTS www.ti.com

PowerPAD[™] TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

PowerPAD is a trademark of Texas Instruments.

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-153.
- 5. Features may differ or may not be present.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
- 8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 (www.ti.com/lit/slma002) and SLMA004 (www.ti.com/lit/slma004).
- 9. Size of metal pad may vary due to creepage requirement.
- 10. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 12. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2025. Texas Instruments Incorporated